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STMicroelectronics STPS80H100CY

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## STPS80H100C

## High voltage power Schottky rectifier

#### **Features**

- High reverse voltage
- Negligible switching losses
- Low forward voltage drop
- Low leakage current
- High temperature
- Low thermal resistance
- Avalanche capability specified

#### **Description**

Dual center tap Schottky rectifier suited for Switched Mode Power Supplies and high frequency DC to DC converters.

Packaged in Max247, this device is intended for use in high frequency computer and telecom converters.

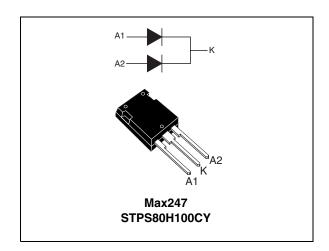


Table 1. Device summary

Symbol	Value
I <sub>F(AV)</sub>	2 x 40 A
V <sub>RRM</sub>	100 V
T <sub>j</sub> (max)	175 °C
V <sub>F</sub> (max)	0.70 V

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#### 1 Characteristics

Table 2. Absolute ratings (limiting values, per diode)

Symbol	Paramete	Value	Unit		
$V_{RRM}$	Repetitive peak reverse voltage			100	V
I <sub>F(RMS)</sub>	Forward rms current			50	Α
I <sub>F(AV)</sub>	Average forward current	$T_c = 155  ^{\circ}\text{C}$ Per diode $\delta = 0.5$ Per device		40 80	Α
I <sub>FSM</sub>	Surge non repetitive forward current	$t_p = 10 \text{ ms sir}$	nusoidal	400	Α
I <sub>RRM</sub>	Repetitive peak reverse current	$t_p = 2 \mu s, F = 0$	1 kHz	2	Α
P <sub>ARM</sub>	Repetitive peak avalanche power $t_p = 1 \mu s$ , $T_j = 25 °C$			39200	W
T <sub>stg</sub>	Storage temperature range			-65 to + 175	Ô
T <sub>j</sub>	Maximum operating junction temperature <sup>(1)</sup>			175	°C
dV/dt	Critical rate of rise of reverse voltage			10000	V/µs

<sup>1.</sup>  $\frac{dPtot}{dT_j} < \frac{1}{Rth(j-a)}$  condition to avoid thermal runaway for a diode on its own heatsink

Table 3. Thermal resistance

Symbol	Parameter	Value	Unit	
R <sub>th(j-c)</sub>	Junction to case Per Tota	diode al	0.7 0.5	°C/W
R <sub>th(c)</sub>	Coupling		0.3	

When the diodes 1 and 2 are used simultaneously:

 $\Delta T_j(diode 1) = P(diode 1) \times R_{th(j-c)}(Per diode) + P(diode 2) \times R_{th(c)}$ 

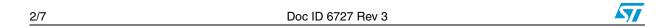
Table 4. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
ı_(1)	I <sub>R</sub> <sup>(1)</sup> Reverse leakage current	T <sub>j</sub> = 25 °C	$V_R = V_{RRM}$			20	μΑ
'R'		T <sub>j</sub> = 125 °C			7	20	mA
	/ <sub>F</sub> <sup>(2)</sup> Forward voltage drop	T <sub>j</sub> = 25 °C	I <sub>F</sub> = 40 A			0.8	
V <sub>E</sub> <sup>(2)</sup>		T <sub>j</sub> = 125 °C	I <sub>F</sub> = 40 A		0.65	0.7	V
VF. 7   Forward voltage drop	T <sub>j</sub> = 25 °C	I <sub>F</sub> = 80 A			0.94	V	
		T <sub>j</sub> = 125 °C	I <sub>F</sub> = 80 A		0.79	0.84	

<sup>1.</sup> Pulse test:  $t_p = 5$  ms,  $\delta < 2\%$ 

To evaluate the conduction losses use the following equation:

$$P = 0.5 \times I_{F(AV)} + 0.0055 I_{F}^{2}_{(RMS)}$$

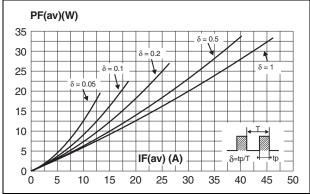


<sup>2.</sup> Pulse test:  $t_p = 380 \mu s$ ,  $\delta < 2\%$ 

STPS80H100C Characteristics

Figure 1. Average forward power dissipation Figure 2. versus average forward current (per diode)

gure 2. Average forward current versus ambient temperature  $(\delta = 0.5, \text{ per diode})$ 



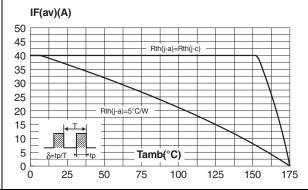
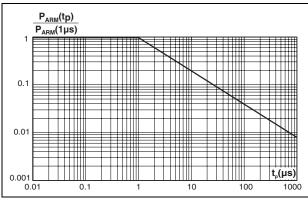


Figure 3. Normalized avalanche power derating versus pulse duration

Figure 4. Normalized avalanche power derating versus junction temperature



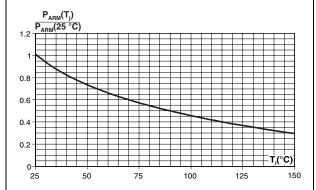
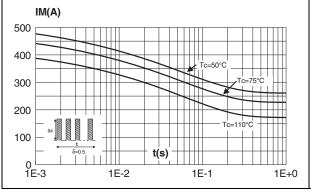
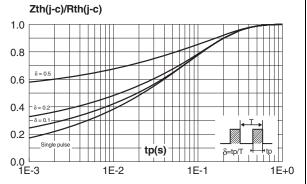


Figure 5. Non repetitive surge peak forward current versus overload duration (maximum values, per diode)

Figure 6. Relative variation of thermal impedance junction to case versus pulse duration (per diode)





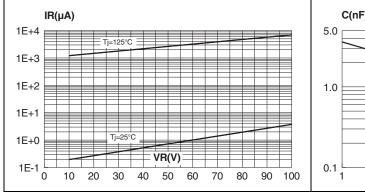
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Figure 7. Reverse leakage current versus reverse voltage applied (typical values, per diode)

Figure 8. Junction capacitance versus reverse voltage applied (typical values, per diode)



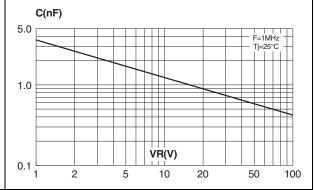
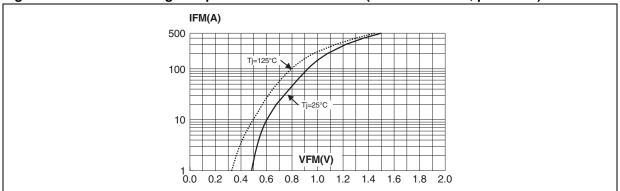


Figure 9. Forward voltage drop versus forward current (maximum value, per diode)



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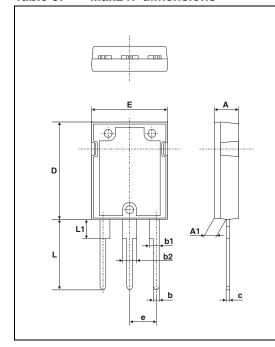
STPS80H100C Package information

### 2 Package information

- Epoxy meets UL94, V0
- Lead-free packages

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: <a href="https://www.st.com">www.st.com</a>. ECOPACK<sup>®</sup> is an ST trademark.

Table 5. Max247 dimensions



	Dimensions				
Ref.	Millimeters		Inches		
	Min.	Max.	Min.	Max.	
Α	4.70	5.30	0.185	0.209	
A1	2.20	2.60	0.087	0.102	
b	1.00	1.40	0.038	0.055	
b1	2.00	2.40	0.079	0.094	
b2	3.00	3.40	0.118	0.133	
С	0.40	0.80	0.016	0.031	
D	19.70	20.30	0.776	0.799	
е	5.35	5.55	0.211	0.219	
Е	15.30	15.90	0.602	0.626	
L	14.20	15.20	0.559	0.598	
L1	3.70	4.30	0.146	0.169	





**Ordering information** 

STPS80H100C

# 3 Ordering information

Table 6. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS80H100CY	STPS80H100CY	Max247	4.4 g	30	Tube

# 4 Revision history

Table 7. Document revision history

Date	Revision	Change
July-2003	2B	Last release.
21-Jun-2010	3	Updated package illustration on page 1 and Section 2: Package information on page 5.

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#### Distributor of STMicroelectronics: Excellent Integrated System Limited Datasheet of STPS80H100CY - DIODE ARRAY SCHOTTKY 100V MAX247

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#### STPS80H100C

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